

Data sheet acquired from Harris Semiconductor

CD74AC74, CD74ACT74

Dual D-Type Flip-Flop with Set and Reset Positive-Edge-Triggered

September 1998

Features

- · Buffered Inputs
- Typical Propagation Delay (AC00)
 - 4.9ns at $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 50pF$
- Exceeds 2kV ESD Protection MIL-STD-883, Method 3015
- SCR-Lachup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
 - Fanout to 15 FAST™ ICs
 - Drives 50Ω Transmission Lines

Description

The Harris CD74AC74 and CD74ACT74 dual D-type, positive edge triggered flip-flops use the Harris ADVANCED CMOS technology. These flip-flops have independent DATA, $\overline{\text{SET}}$, $\overline{\text{RESET}}$, and CLOCK inputs and Q and $\overline{\text{Q}}$ outputs. The logic level present at the data input is transferred to the output during the positive going transition of the clock pulse. $\overline{\text{SET}}$ and $\overline{\text{RESET}}$ are independent of the clock and are accomplished by a low level at the appropriate input.

Ordering Information

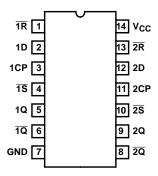
PART NUMBER	TEMP. RANGE (^O C)	PACKAGE	PKG. NO.
CD74AC74E	0 to 70, -40 to 85 -55 to 125	14 Ld PDIP	E14.3
CD74ACT74E	0 to 70, -40 to 85 -55 to 125	14 Ld PDIP	E14.3
CD74AC74EX	0 to 70, -40 to 85 -55 to 125	14 Ld PDIP	E14.3
CD74ACT74EX	0 to 70, -40 to 85 -55 to 125	14 Ld PDIP	E14.3
CD74AC74M	0 to 70, -40 to 85 -55 to 125	14 Ld SOIC	M14.15
CD74ACT74M	0 to 70, -40 to 85 -55 to 125	14 Ld SOIC	M14.15

NOTES:

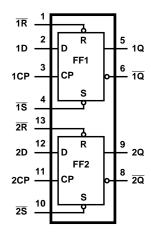
- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

Pinout

CD74AC74, CD74ACT74 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

	INP	OUTPUTS			
SET	RESET	СР	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	H (Note 5)	H (Note 5)
Н	Н	1	Н	Н	L
Н	Н	↑	L	L	Н
Н	Н	L	Х	Q0	Q0

NOTES:

- 3. H = High level (steady state), L = Low level (steady state), X = Don't care, ↑ = Transition from Low to High level.
- 4. Q0 = the level of Q before the indicated input conditions were established.
- 5. This configuration is nonstable, that is, it will not persist when set and reset inputs return to their inactive (high) level.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 6V
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±50mA
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
DC V _{CC} or Ground Current, I _{CC or} I _{GND} (Note 6) ±100mA

Thermal Information

Thermal Resistance (Typical, Note 8) θ_{JA} (°C/W)
PDIP Package 90
SOIC Package
Maximum Junction Temperature (Plastic Package) 150°C
Maximum Storage Temperature Range65°C to 150°C
Maximum Lead Temperature (Soldering 10s)300°C

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC} (Note 7)
AC Types
ACT Types
DC Input or Output Voltage, V _I , V _O
Input Rise and Fall Slew Rate, dt/dv
AC Types, 1.5V to 3V 50ns (Max)
AC Types, 3.6V to 5.5V
ACT Types, 4.5V to 5.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 6. For up to 4 outputs per device, add ± 25 mA for each additional output.
- 7. Unless otherwise specified, all voltages are referenced to ground.
- 8. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

			ST ITIONS	V _{CC} 25°C		V _{CC} 25°C -40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(v)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES											
High Level Input Voltage	V _{IH}	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V _{IL}	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	Voн	V _{IH} or V _{IL}	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 9, 10)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 9, 10)	5.5	-	-	-	-	3.85	-	V

DC Electrical Specifications (Continued)

		TEST CONDITIONS		V _{CC} 2		25°C		C TO °C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	V_{OL}	V _{IH} or V _{IL}	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	1	0.36	-	0.44	-	0.5	٧
			75 (Note 9, 10)	5.5	-	-	-	1.65	-	1	V
			50 (Note 9, 10)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	I _I	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μΑ
Quiescent Supply Current, FF	Icc	V _{CC} or GND	0	5.5	-	4	-	40	-	80	μΑ
ACT TYPES											
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 9, 10)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 9, 10)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V _{OL}	V _{IH} or V _{IL}	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	1	0.36	-	0.44	-	0.5	٧
			75 (Note 9, 10)	5.5	-	-	-	1.65	-	-	٧
			50 (Note 9, 10)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	II	V _{CC} or GND	-	5.5	1	±0.1	-	±1	-	±1	μΑ
Quiescent Supply Current, FF	Icc	V _{CC} or GND	0	5.5	-	4	-	40	-	80	μΑ
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

NOTES:

- 9. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 10. Test verifies a minimum 50Ω transmission-line-drive capability at 85° C, 75Ω at 125° C.

ACT Input Load Table

INPUT	UNIT LOAD
D	0.53
R, S	0.58
СР	1

NOTE: Unit load is ΔI_{CC} limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

Prerequisite For Switching Function

			-40°C	ГО 85 ⁰ С	-55°C TO 125°C		
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	UNITS
AC TYPES							
Data to CP Setup Time	t _{SU}	1.5	39	-	44	-	ns
		3.3 (Note 11)	4.3	-	4.9	-	ns
		5 (Note 12)	3.1	-	3.5	-	ns
Hold Time	t _H	1.5	0	-	0	-	ns
		3.3	0	-	0	-	ns
		5	0	-	0	-	ns
Removal Time, R, S to CP	t _{REM}	1.5	30	-	34	-	ns
		3.3	4.1	-	4.7	-	ns
		5	2.4	-	2.7	-	ns
Pulse Width, R, S	t _W	1.5	44	-	50	-	ns
		3.3	4.9	-	5.6	-	ns
		5	3.5	-	4	-	ns
Pulse Width, CP	t _W	1.5	49	-	56	-	ns
		3.3	5.5	-	6.3	-	ns
		5	3.9	-	4.5	-	ns
CP Frequency	f _{MAX}	1.5	10	-	9	-	MHz
		3.3	90	-	79	-	MHz
		5	125	-	110	-	MHz
ACT TYPES	•	•		•	•	•	
Data to CP Setup Time	tsu	5 (Note 12)	3.5	-	4	-	ns
Hold Time	tH	5	0	-	0	-	ns
Removal Time, R, S to CP	t _{REM}	5	2.4	-	2.7	-	ns
Pulse Width, R, S	t _W	5	4.4	-	5	-	ns
Pulse Width, CP	t _W	5	5	-	5.7	-	ns
CP Frequency	f _{MAX}	5	97	-	85	-	MHz

NOTES:

11. 3.3V Min at 3.6V.

12. 5V Min at 4.5V.

Switching Specifications Input t_{r} , t_{f} = 3ns, C_{L} = 50pF (Worst Case)

			-40°C TO 85°C		-55				
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay, CP to Q, \overline{Q}	t _{PLH} , t _{PHL}	1.5	-	-	114	-	-	125	ns
		3.3 (Note 14)	3.6	-	12.7	3.5	-	14	ns
		5 (Note 15)	2.6	-	9.1	2.5	-	10	ns

Switching Specifications Input $t_{\rm f},\,t_{\rm f}$ = 3ns, C_L = 50pF (Worst Case) (Continued)

			-40°C TO 85°C		-55				
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Propagation Delay, \overline{R} , \overline{S} to Q , \overline{Q}	t _{PLH}	1.5	-	-	120	-	-	132	ns
		3.3	3.8	-	13.4	3.7	-	14.7	ns
		5	2.7	-	9.5	2.6	-	10.5	ns
	t _{PHL}	1.5	-	-	131	-	-	144	ns
		3.3	4.1	-	14.6	4	-	16.1	ns
		5	3	-	10.4	2.9	-	11.5	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 16)	-	-	55	-	-	55	-	pF
ACT TYPES				•	•		•	•	•
Propagation Delay, CP to Q, $\overline{\mathbf{Q}}$	t _{PHL} t _{PLH}	5 (Note 15)	2.5	-	8.6	2.4	-	9.5	ns
Propagation Delay, \overline{R} , \overline{S} to Q , \overline{Q}	t _{PLH}	5	3	-	10.5	2.9	-	11.5	ns
	t _{PHL}	5	3.2	-	11.4	3.1	-	12.5	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 16)	-	-	55	-	-	55	-	pF

NOTES:

- 13. Limits tested 100%.
- 14. 3.3V Min at 3.6V, Max at 3V.
- 15. 5V Min at 5.5V, Max at 4.5V.
- 16. C_{PD} is used to determine the dynamic power consumption per flip-flop. $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o) + V_{CC} \Delta I_{CC}$ where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.

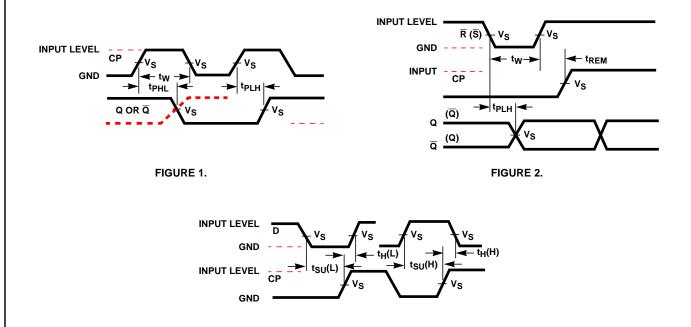
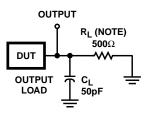


FIGURE 3.



NOTE: For AC Series Only: When V_{CC} = 1.5V, R_L = 1k Ω .

	CD74AC	CD74ACT
Input Level	V _{CC}	3V
Input Switching Voltage, V _S	0.5 V _{CC}	1.5V
Output Switching Voltage, V _S	0.5 V _{CC}	0.5 V _{CC}

FIGURE 4. PROPAGATION DELAY TIMES

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